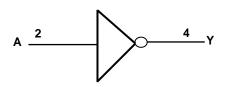


SINGLE INVERTER GATE

Pin Descriptions

Pin Name	Description			
NC	No connection			
А	Data Input			
GND	Ground			
Y	Data Output			
Vcc	Supply Voltage			

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н



SINGLE INVERTER GATE

Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
Ι _{ΟΚ}	Output Clamp Current	-50	mA
Ι _Ο	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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SINGLE INVERTER GATE

Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit	
		Operating	1.4	5.5	V	
V _{cc}	Operating Voltage	Data retention only	1.2		V	
		$V_{\rm CC} = 1.4$ V to 1.95 V	0.65 X V _{CC}			
		$V_{\rm CC}$ = 2.3 V to 2.7 V	1.7		Ň	
VIH	High-level Input Voltage	$V_{CC} = 3 V$ to 3.6 V	2		V	
		$V_{\rm CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7 X V _{CC}			
		$V_{\rm CC} = 1.4$ V to 1.95 V		0.35 X V_{CC}		
N/	V _{IL} Low-level input voltage	$V_{\rm CC}$ = 2.3 V to 2.7 V		0.7	V	
VIL		$V_{CC} = 3 V$ to 3.6 V		0.8	V	
		$V_{\rm CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.3 X V _{CC}		
VI	Input Voltage	•	0	5.5	V	
Vo	Output Voltage		0	V _{cc}	V	
	High-level output current	Vcc=1.4 V		-3		
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V		-8		
I _{OH}				-16	mA	
		$V_{CC} = 3 V$		-24		
		$V_{\rm CC} = 4.5 \text{ V}$		-32		
		Vcc=1.4 V		3		
		V _{CC} = 1.65 V		4		
		V _{CC} = 2.3 V		8	mA	
I _{OL}	Low-level output current			16		
		$V_{CC} = 3 V$		24		
		V _{CC} = 4.5 V		32		
		$V_{CC} = 1.4 \text{ to } 3V$		20		
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
	rate	$V_{CC} = 5 V \pm 0.5 V$		5		
T _A	Operating free-air temperature		-40	85	٥C	

Note: 4. Unused inputs should be held at Vcc or Ground.



SINGLE INVERTER GATE

Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25° C)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit	
		I _{OH} = -100μA	1.4 V to 5.5V	$V_{CC} - 0.1$				
		I _{OH} = -3mA	1.4 V	1.05				
		I _{OH} = -4mA	1.65 V	1.2				
V _{OH}	High Level Output Voltage	I _{OH} = -8mA	2.3V	1.9			V	
	Vollage	I _{OH} = -16mA	3 V	2.4				
		I _{OH} = -24mA	5 V	2.3				
		I _{OH} = -32mA	4.5 V	3.8				
		I _{OL} = 100μA	1.4 V to 5.5V			0.1		
		$I_{OL} = 3mA$	1.4V			.4		
		$I_{OL} = 4mA$	1.65 V			0.45		
V _{OL}	High-level Input Voltage	$I_{OL} = 8mA$	2.3V			0.3	V	
		I _{OL} = 16mA	3 V			0.4		
		$I_{OL} = 24mA$	5 V			0.55		
		$I_{OL} = 32mA$	4.5			0.55		
l _i	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μA	
I _{OFF}	Power Down Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0			± 10	μA	
I _{CC}	Supply Current	$V_1 = 5.5V \text{ of GND}$ $I_0=0$	1.4 V to 5.5V			10	μA	
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	3.3		3.5		pF	
		SOT25	(Note 5)		204			
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W	
	Junction-to-Amplent	DFN1410	(Note 5)		430		1	
		SOT25	(Note 5)		52			
θ_{JC}	Thermal Resistance Junction-to-Case	SOT353	(Note 5)		143		°C/W	
	Juncil011-10-Case	DFN1410	(Note 5)		190		1	

Over recommended free-air temperature range (unless otherwise noted)

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



SINGLE INVERTER GATE

Switching Characteristics

Ра	rameter	er From TO		Vcc = ± 0			1.8 V .15V		2.5 V 0.2V		: 3.3 V).3V		= 5 V).5V	Unit
(Inp	(Input)	nput) (OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Мах	Min	Max		
	t _{pd}	А	Y	2	6.4	1.4	4.4	0.8	3.3	0.5	2.7	0.5	2.7	ns

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	meter From TO		Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		: 3.3 V).3V		= 5 V).5V	Unit
r arameter	(Input)	(Input) (OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Мах	Min	Мах	•••••
t _{pd}	А	Y	3	7.5	2.1	5.2	1.1	4.1	0.8	3.4	0.9	3.3	ns

Operating Characteristics

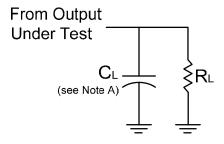
 $T_A = 25 \ ^{o}C$

Р	arameter		Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
-	Conditions		TYP	ТҮР	TYP	ТҮР	TYP	•
C _{pd}	Power dissipation capacitance	f = 10 MHz	16	16	18	18	20	pF

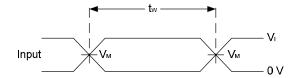


SINGLE INVERTER GATE

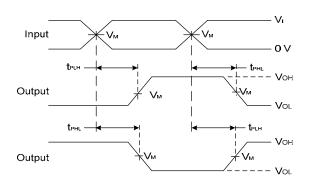
Parameter Measurement Information



Vcc	Vcc		N.,	C.	Р.	
VCC	VI	t _r /t _f	V _M	CL	RL	
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ	
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	15pF	1MΩ	
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1MΩ	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1MΩ	



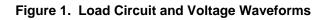
Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

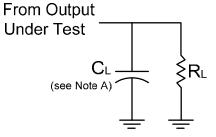
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



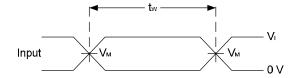


SINGLE INVERTER GATE

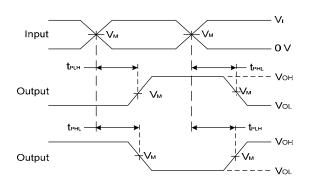
Parameter Measurement Information (Continued)



Vcc	Inp	outs	V _M	CL	RL	
	Vi	t _r /t _f	- 141	υĽ		
1.5V±0.1V	V _{cc}	≤2ns	V _{CC} /2	30pF	1KΩ	
1.8V±0.15V	V _{cc}	≤2ns	V _{CC} /2	30pF	1KΩ	
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	30pF	500Ω	
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω	



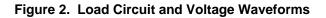
Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

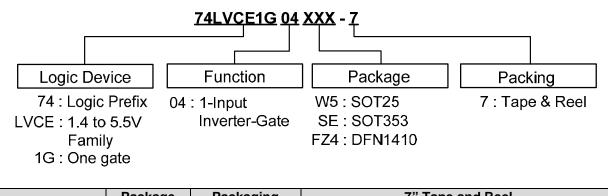
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$





SINGLE INVERTER GATE

Ordering Information



	Device	Package	Packaging	7" Tape a	nd Reel
		Code	(Note 5)	Quantity	Part Number Suffix
Pb ,	74LVCE1G04W5-7	W6	SOT25	3000/Tape & Reel	-7
Pb ,	74LVCE1G04SE-7	SE	SOT353	3000/Tape & Reel	-7
Pb,	74LVCE1G04FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

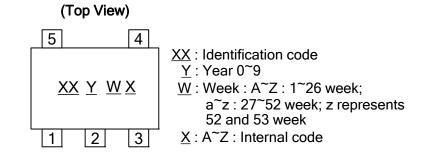
Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



SINGLE INVERTER GATE

Marking Information

(1) SOT25 and SOT353



	Part Number	Package	Identification Code	
7	74LVCE1G04W5	SOT25	PU	
	74LVCE1G04SE	SOT353	PV	

(2) DFN1410H4-6

(Top View)



- \underline{XX} : Identification Code \underline{Y} : Year : 0~9
- \overline{W} : Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week
- \underline{X} : A~Z : Internal code

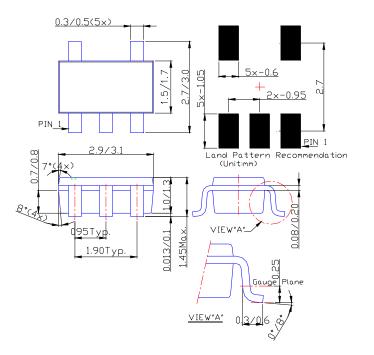
Part Number	Package	Identification Code
74LVCE1G04FZ4	DFN1410	PU



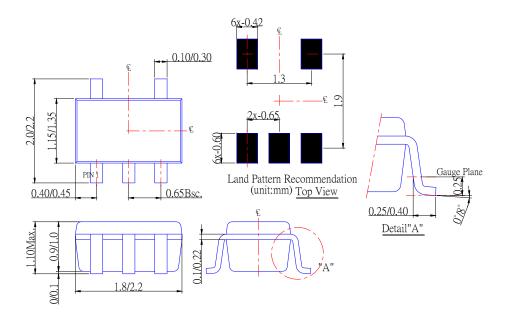
SINGLE INVERTER GATE

Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353



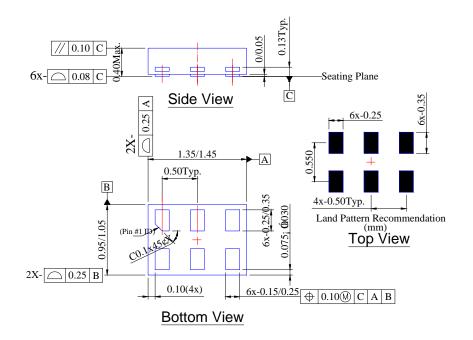
74LVCE1G04 Document number: DS32212 Rev. 2 - 2



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Package Outline Dimensions (All Dimensions in mm)

(3) Package Type: DFN1410

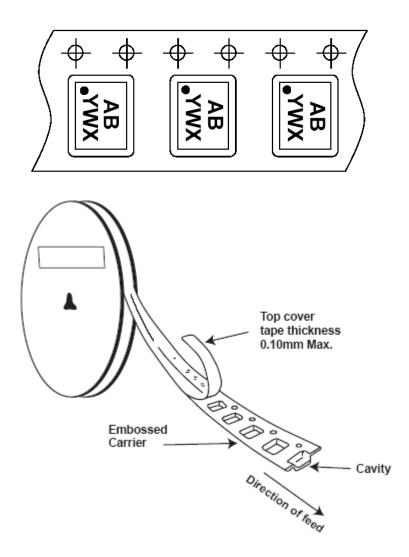




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Taping Orientation (Note 7)

For DFN1410







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